

Piezoelectric Material



Features

- Suitable for precision motion
- Wide range of application fields
- Vacuum compatible, not affected by electromagnetic interference
- Possesses a certain level of mechanical strength and high compressive resistance

Description

Piezoelectric materials can generate an electric field due to mechanical deformation, and they can also undergo mechanical deformation in response to an applied electric field. This inherent electromechanical coupling effect has led to widespread applications of piezoelectric materials in engineering. For instance, active vibration damping, noise control, non-destructive testing, and ultrasound imaging, among others.

Discover the precision engineering of YINGUAN Company's piezoelectric devices, meticulously crafted with state-of-the-art lead zirconate titanate (PZT) material.

Experience unparalleled accuracy in driving mechanical components, designed to deliver exceptional ultra-precision positioning for the most discerning international clients.

Elevate your projects with our cutting-edge technology.

Technical Specifications

	Symbol	YGP-51	YGP-51A	YGP-51H	Unit
Electrical property					
Permittivity	ϵ_{33}^T	1900	2600	4200	
Dielectric loss	tg^δ	<2.5	<2.5	<2.5	%
Electromechanical property					
Electro-mechanical coupling factor	K_p	0.65	0.66	0.69	
	K_{31}	0.37	0.39	0.42	
	K_{33}	0.72	0.77	0.78	
	K_T	0.50	0.48	0.50	
Piezoelectric Constant	d_{31}	-320	-220	-300	10^{-12} C/N
	d_{33}	440	560	750	10^{-12} C/N
	g_{31}	-11	-10	-9	10^{-3} Vm/N
	g_{33}	17.8	22.3	16.8	10^{-3} Vm/N

Technical Specifications(Continued from previous page)

	Symbol	YGP-51	YGP-51A	YGP-51H	Unit
Frequency constant	N_p	2010	1980	2000	kHz·mm
	N_t	1950	2040	2030	kHz·mm
	N_{31}	1400	1400	/	kHz·mm
	N_{33}	1500	1350	/	kHz·mm
Physical property					
Mechanical quality factor	Q_m	80	90	60	
Density	ρ	7.74	7.85	7.75	10^3Kg/m^3
Elastic compliance	S^{E11}	17	16	17	$10^{-12} \text{m}^2/\text{N}$
	S^{E33}	21	19	21	$10^{-12} \text{m}^2/\text{N}$
Curie temperature	T_c	320	300	190	$^{\circ}\text{C}$
Process characteristic					
Sintering temperature	T_s	1050	1250	1050	$^{\circ}\text{C}$